



# UT7422

**Power MOSFET**

## 40A, 30V N-CHANNEL POWER MOSFET

### DESCRIPTION

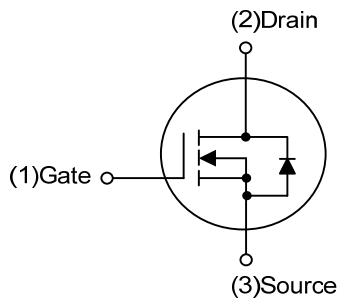
The UTC **UT7422** is a N-channel Power Mosfet, it uses UTC's advanced technology to provide the customers with a minimum on state resistance, etc.

The UTC **UT7422** is suitable for load switch and battery protection applications.

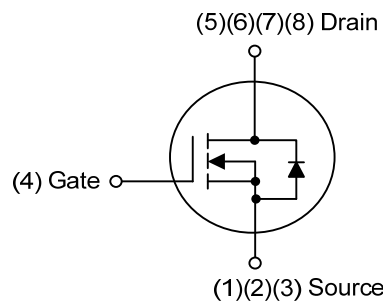
### FEATURES

- \*  $R_{DS(ON)} \leq 5.6 \text{ m}\Omega$  @  $V_{GS}=10V, I_D=20A$
- $R_{DS(ON)} \leq 9.6 \text{ m}\Omega$  @  $V_{GS}=4.5V, I_D=16A$
- \* Low  $R_{DS(ON)}$

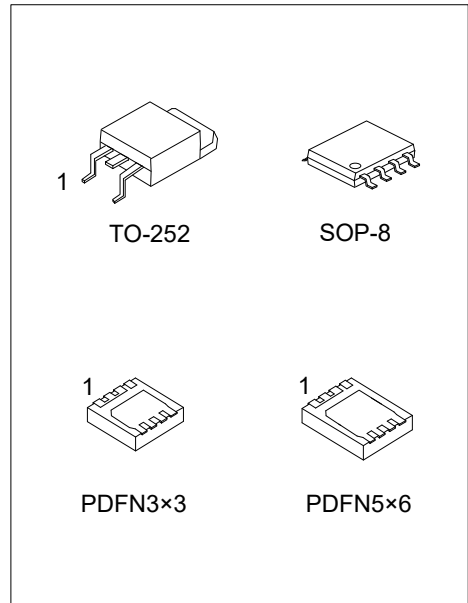
### SYMBOL



TO-252



SOP-8/PDFN3×3/PDFN5×6



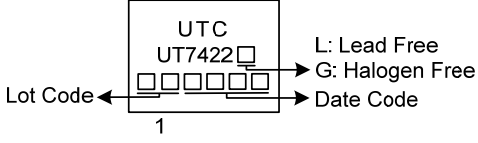
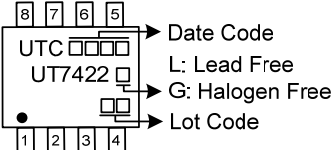
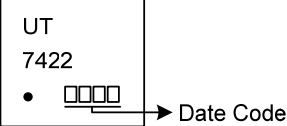
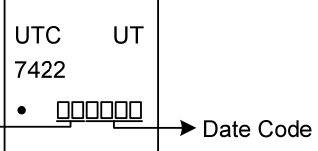
### ORDERING INFORMATION

Ordering Number		Package	Pin Assignment								Packing
Lead Free	Halogen Free		1	2	3	4	5	6	7	8	
UT7422L-TN3-R	UT7422G-TN3-R	TO-252	G	D	S	-	-	-	-	-	Tape Reel
UT7422L-S08-R	UT7422G-S08-R	SOP-8	S	S	S	G	D	D	D	D	Tape Reel
UT7422L-P3030-R	UT7422G-P3030-R	PDFN3×3	S	S	S	G	D	D	D	D	Tape Reel
UT7422L-P5060-R	UT7422G-P5060-R	PDFN5×6	S	S	S	G	D	D	D	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

<p>UT7422G-TN3-R</p> <ul style="list-style-type: none"> <li>(1) Packing Type</li> <li>(2) Package Type</li> <li>(3) Green Package</li> </ul>	<ul style="list-style-type: none"> <li>(1) R: Tape Reel</li> <li>(2) TN3: TO-252, S08: SOP-8, P3030: PDFN3×3 P5060: PDFN5×6</li> <li>(3) G: Halogen Free and Lead Free, L: Lead Free</li> </ul>
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■ MARKING

TO-252	SOP-8
 <p>UTC UT7422 □ □ □ □ □ □ □ 1</p> <p>Lot Code ←</p> <p>→ L: Lead Free → G: Halogen Free → Date Code</p>	 <p>8 7 6 5 UTC □ □ □ □ □ □ UT7422 □ □ □ □ □ □ □ □ □ □ □ □ 1 2 3 4</p> <p>→ Date Code → L: Lead Free → G: Halogen Free → Lot Code</p>
PDFN3×3	PDFN5×6
 <p>UT 7422 • □ □ □ □ □</p> <p>→ Date Code</p>	 <p>UTC UT 7422 • □ □ □ □ □ □ □ □ □ □</p> <p>Lot Code ← → Date Code</p>

■ ABSOLUTE MAXIMUM RATINGS ( $T_A=25^{\circ}\text{C}$ , unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	30	V
Gate-Source Voltage		$V_{GSS}$	$\pm 20$	V
Continuous Drain Current		$I_D$	40	A
Pulsed Drain Current (Note 2)		$I_{DM}$	160	A
Avalanche Energy $L=0.1\text{mH}$ (Note 3)		$E_{AS}$	48	mJ
Power Dissipation	$T_C=25^{\circ}\text{C}$	TO-252	46	W
		SOP-8	1.8	W
		PDFN3x3	28	W
		PDFN5x6	30	W
Junction Temperature		$T_J$	-55 ~ +150	$^{\circ}\text{C}$
Storage Temperature Range		$T_{STG}$	-55 ~ +150	$^{\circ}\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Pulse width limited by maximum junction temperature

3.  $L = 0.1\text{mH}$ ,  $I_{AS} = 31\text{A}$ ,  $V_{DD} = 20\text{V}$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^{\circ}\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-252	$\theta_{JA}$	50	$^{\circ}\text{C/W}$
	SOP-8		90	$^{\circ}\text{C/W}$
	PDFN3x3		60	$^{\circ}\text{C/W}$
	PDFN5x6		65	$^{\circ}\text{C/W}$
Junction to Case	TO-252	$\theta_{JC}$	2.7	$^{\circ}\text{C/W}$
	SOP-8		69	$^{\circ}\text{C/W}$
	PDFN3x3		4.46	$^{\circ}\text{C/W}$
	PDFN5x6		4.16	$^{\circ}\text{C/W}$

Notes: 1. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

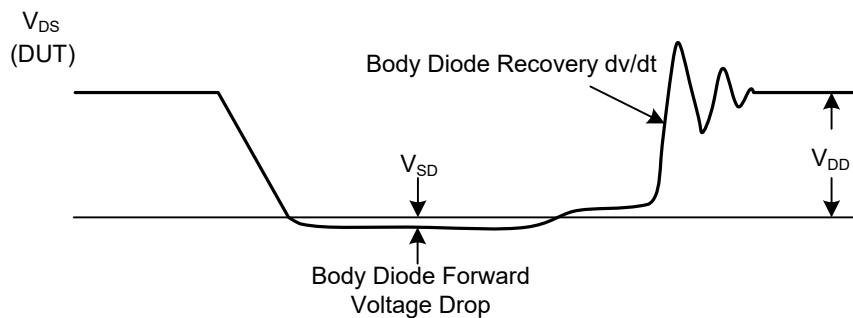
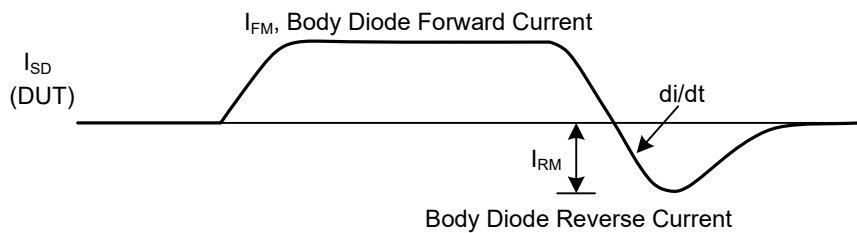
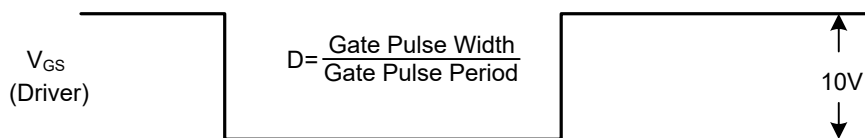
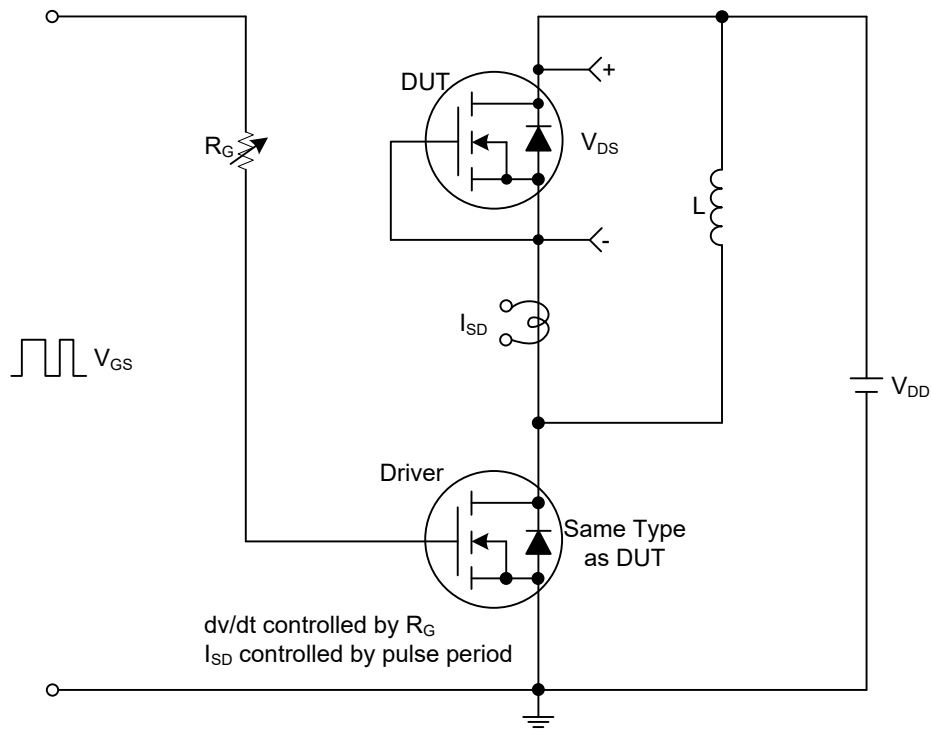
2. The data tested by pulsed, pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .

■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>STATIC PARAMETERS</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	I <sub>D</sub> =250μA, V <sub>GS</sub> =0V	30			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V			1	μA
		V <sub>DS</sub> =30V, V <sub>GS</sub> =0V, T <sub>J</sub> =55°C			5	μA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V			100	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0		3.0	V
Static Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A			5.6	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =16A			9.6	mΩ
<b>DYNAMIC PARAMETERS</b>						
Input Capacitance	C <sub>ISS</sub>	V <sub>GS</sub> =0V, V <sub>DS</sub> =15V, f=1.0MHz		2140		pF
Output Capacitance	C <sub>OSS</sub>			490		pF
Reverse Transfer Capacitance	C <sub>RSS</sub>			425		pF
<b>SWITCHING PARAMETERS</b>						
Total Gate Charge	Q <sub>G</sub>	V <sub>GS</sub> =4.5V, V <sub>DS</sub> =24V, I <sub>D</sub> =40A		33		nC
Gate to Source Charge	Q <sub>GS</sub>			8		nC
Gate to Drain Charge	Q <sub>GD</sub>			17		nC
Turn-ON Delay Time	t <sub>D(ON)</sub>	V <sub>DD</sub> =15V, V <sub>GS</sub> =4.5V, I <sub>D</sub> =40A, R <sub>G</sub> =3Ω (Note 1, 2)		19		ns
Rise Time	t <sub>R</sub>			26		ns
Turn-OFF Delay Time	t <sub>D(OFF)</sub>			35		ns
Fall-Time	t <sub>F</sub>			33		ns
<b>SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS</b>						
Maximum Body-Diode Continuous Current (Note)	I <sub>S</sub>				40	A
Maximum Body-Diode Pulsed Current	I <sub>SM</sub>				160	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V			1	V

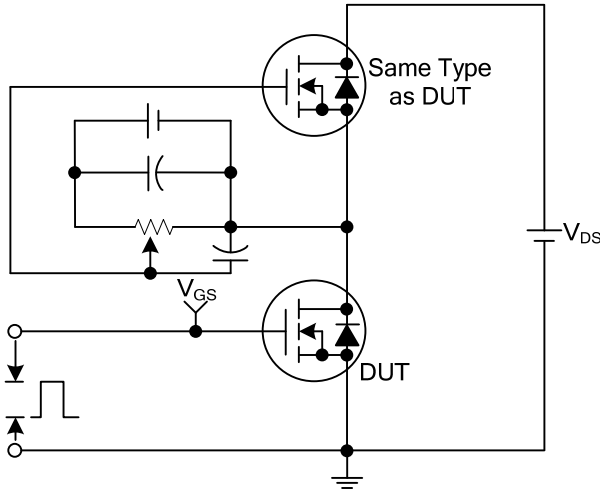
- Notes: 1. Pulse Test : Pulse width ≤ 300μs, Duty cycle ≤ 2%.  
 2. Essentially independent of operating temperature.

## ■ TEST CIRCUITS AND WAVEFORMS

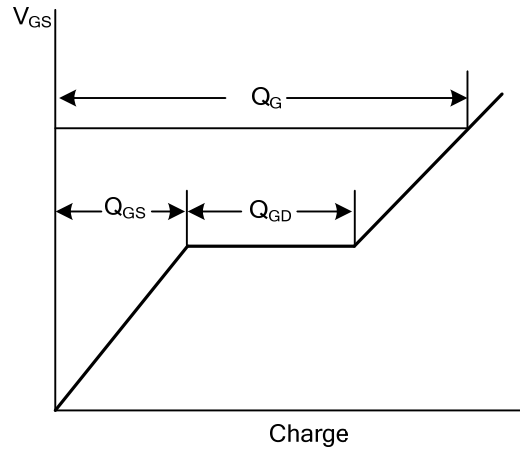


Peak Diode Recovery dv/dt Test Circuit and Waveforms

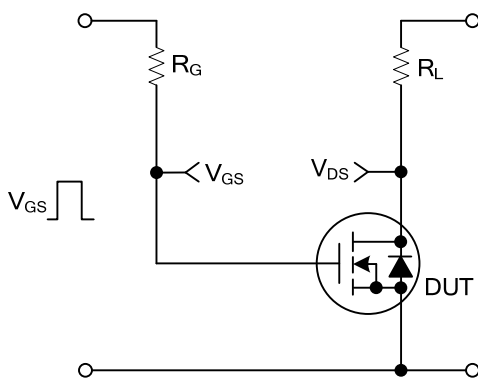
## TEST CIRCUITS AND WAVEFORMS



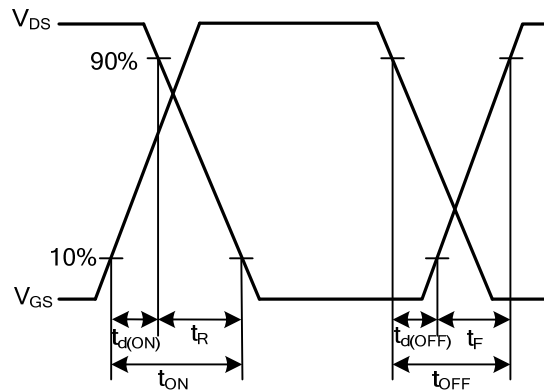
Gate Charge Test Circuit



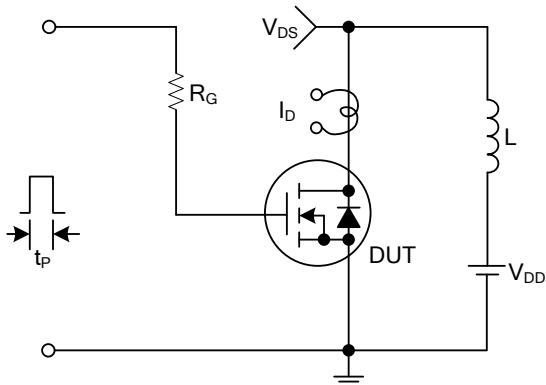
Gate Charge Waveforms



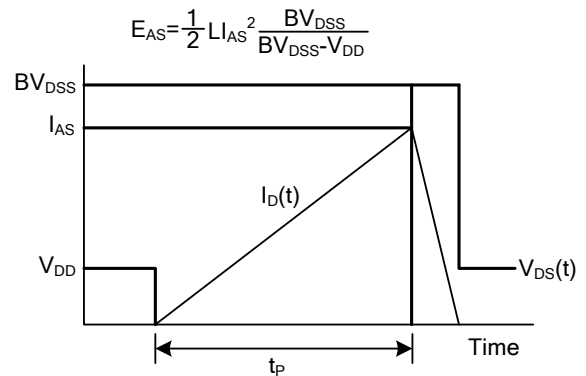
Resistive Switching Test Circuit



Resistive Switching Waveforms

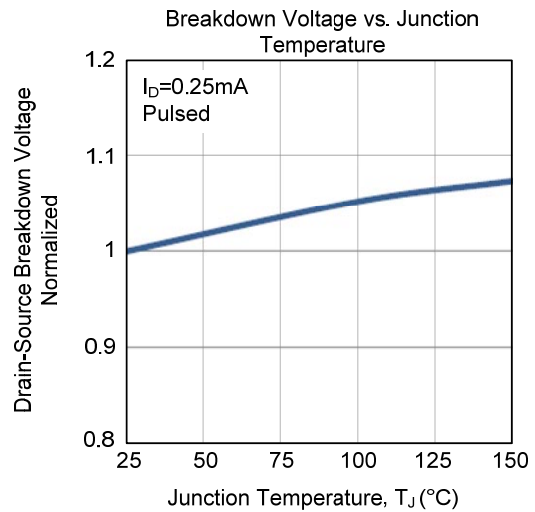
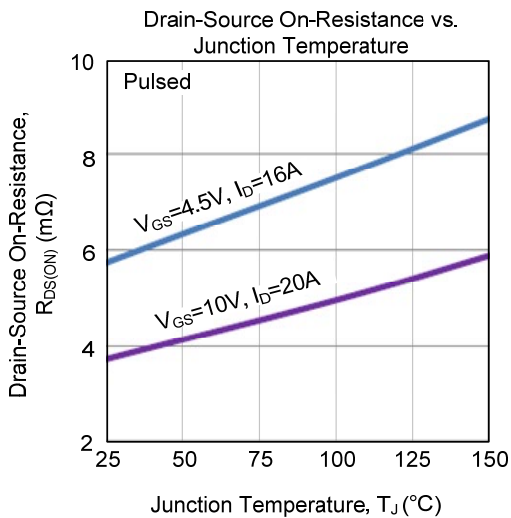
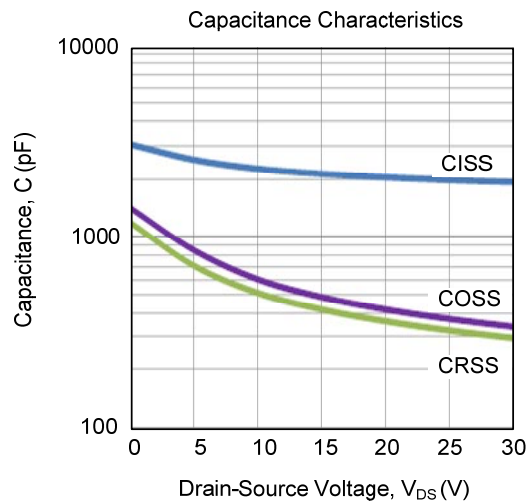
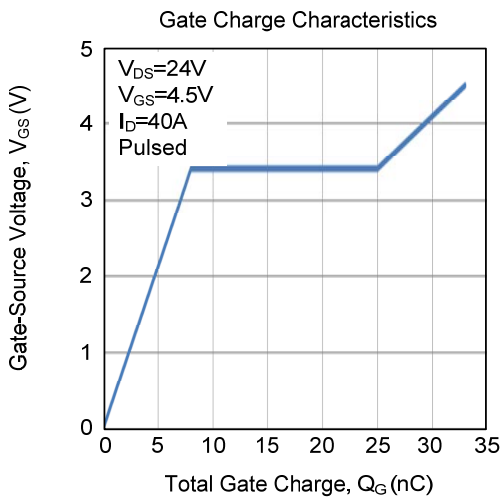
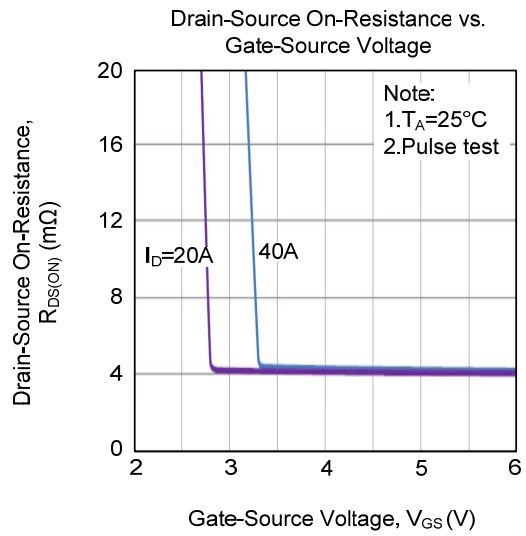
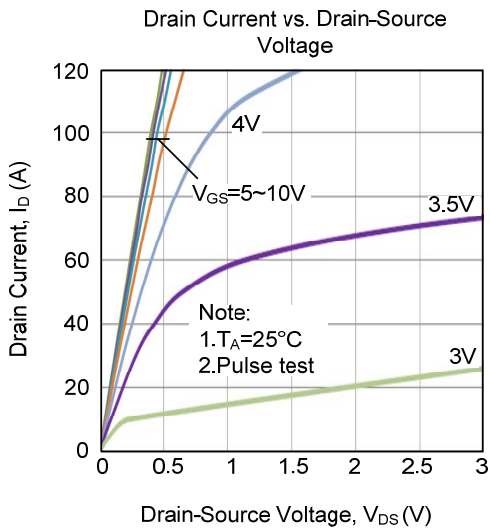


Unclamped Inductive Switching Test Circuit

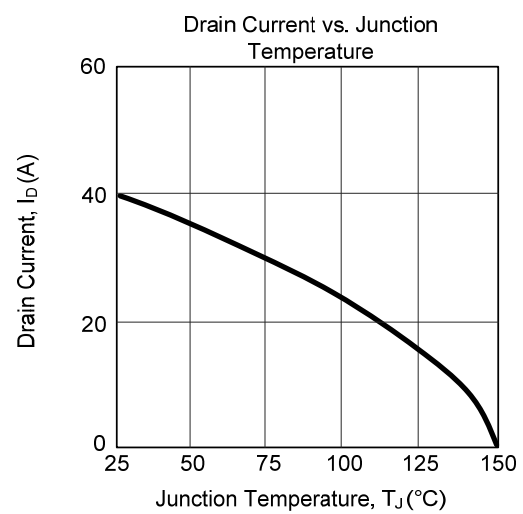
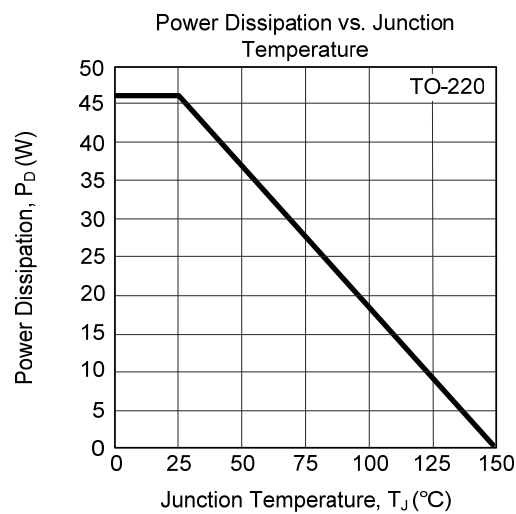
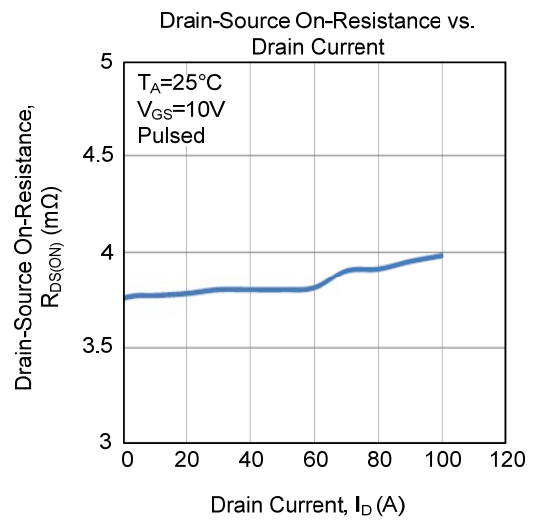
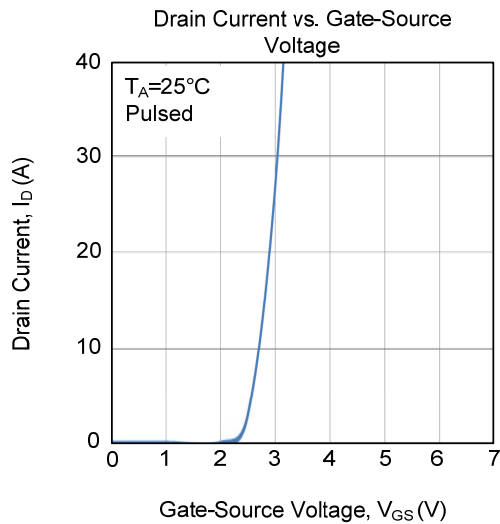
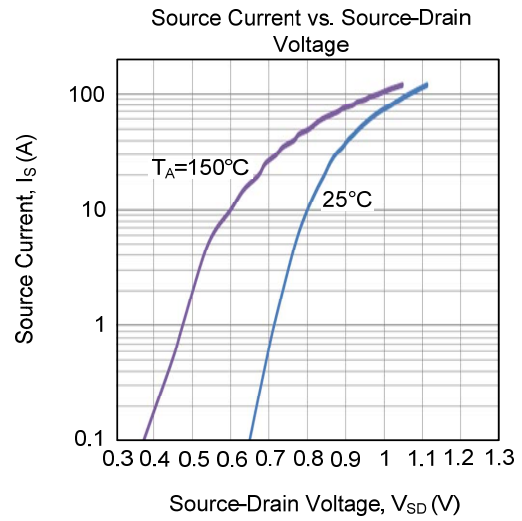
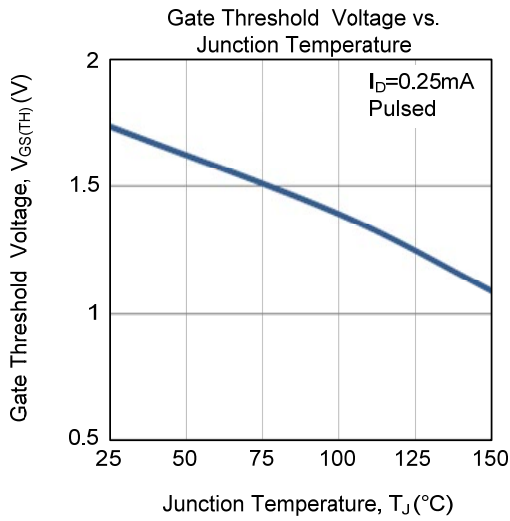


Unclamped Inductive Switching Waveforms

## TYPICAL CHARACTERISTICS

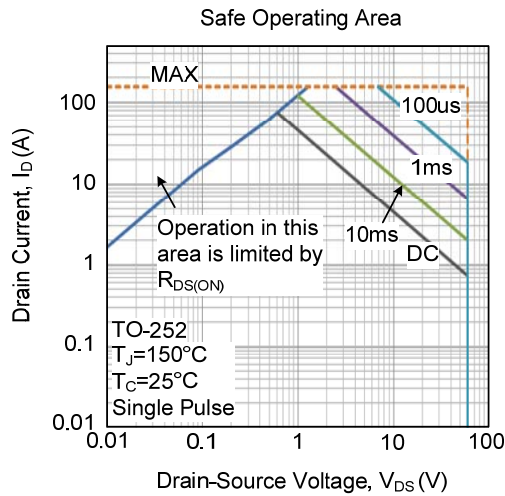


## ■ TYPICAL CHARACTERISTICS (Cont.)





### ■ TYPICAL CHARACTERISTICS (Cont.)



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